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TEXAS INSTRUMENTS

OPA1611, OPA1612

SBOS450C –JULY 2009–REVISED AUGUST 2014

OPA161x SoundPlus™ High-Performance, Bipolar-Input Audio Operational Amplifiers

1 Features

- Superior Sound Quality
- Ultralow Noise: 1.1 nV/√Hz at 1 kHz
- Ultralow Distortion: 0.000015% at 1 kHz
- High Slew Rate: 27 V/µs
- Wide Bandwidth: 40 MHz (G = +1)
- High Open-Loop Gain: 130 dB
- Unity Gain Stable
- Low Quiescent Current: 3.6 mA per Channel
- Rail-to-Rail Output
- Wide Supply Range: ±2.25 V to ±18 V
- Single and Dual Versions Available

2 Applications

- Professional Audio Equipment
- Microphone Preamplifiers
- Analog and Digital Mixing Consoles
- Broadcast Studio Equipment
- Audio Test And Measurement
- High-End A/V Receivers

3 Description

The OPA1611 (single) and OPA1612 (dual) bipolar-input operational amplifiers achieve very low 1.1-nV/√Hz noise density with an ultralow distortion of 0.000015% at 1 kHz. The OPA1611 and OPA1612 offer rail-to-rail output swing to within 600 mV with a 2-kΩ load, which increases headroom and maximizes dynamic range. These devices also have a high output drive capability of ±30 mA.

These devices operate over a very wide supply range of ±2.25 V to ±18 V, on only 3.6 mA of supply current per channel. The OPA1611 and OPA1612 op amps are unity-gain stable and provide excellent dynamic behavior over a wide range of load conditions.
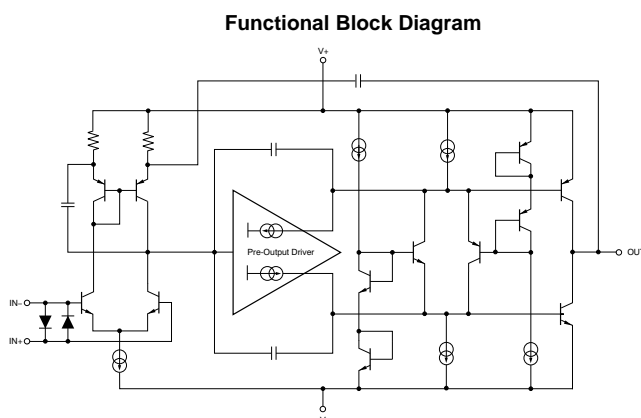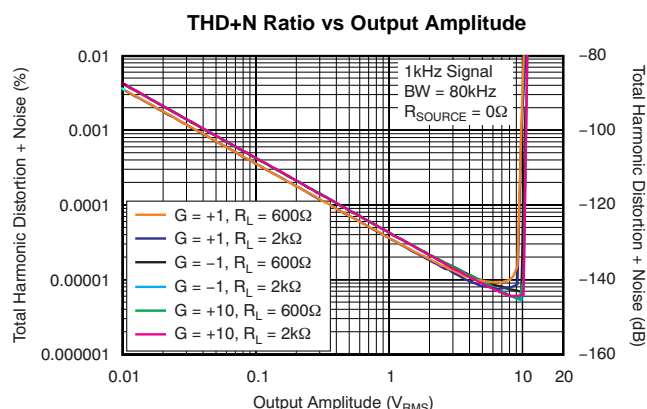
The dual version features completely independent circuitry for lowest crosstalk and freedom from interactions between channels, even when overdriven or overloaded.

Both the OPA1611 and OPA1612 are available in SOIC-8 packages and the OPA1612 is available in SON-8. These devices are specified from –40°C to +85°C.

Device Information[1]

PART NUMBER	PACKAGE	BODY SIZE (NOM)
OPA1611	SOIC (8)	4.90 mm × 3.91 mm
OPA1612	SOIC (8)	4.90 mm × 3.91 mm
	SON (8)	3.00 mm × 3.00 mm

(1) For all available packages, see the orderable addendum at the end of the datasheet.

THD+N Ratio vs Output Amplitude

1kHz Signal
BW = 80kHz
$R_{SOURCE} = 0\Omega$

G = +1, R_L = 600Ω
G = +1, R_L = 2kΩ
G = –1, R_L = 600Ω
G = –1, R_L = 2kΩ
G = +10, R_L = 600Ω
G = +10, R_L = 2kΩ

Functional Block Diagram

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OPA1611, OPA1612

5   Pin Configuration and Functions

D Package
OPA1611, SOIC-8
(Top View)

D Package
OPA1612, SOIC-8
(Top View)

DRG Package
OPA1612, SON-8
(Top View)
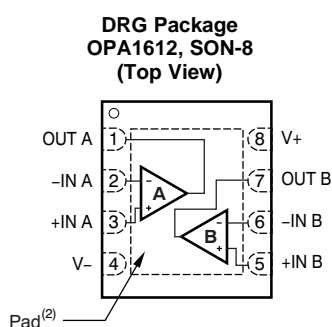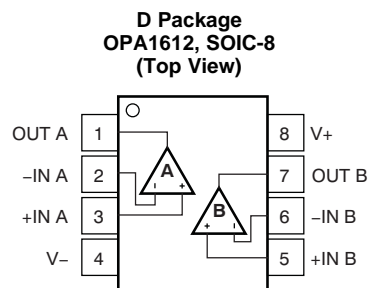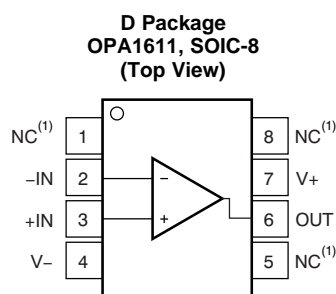
(1) NC denotes no internal connection. Pin can be left floating or connected to any voltage between (V–) and (V+).

(2) Exposed thermal die pad on underside; connect thermal die pad to V–. Soldering the thermal pad improves heat dissipation and provides specified performance.

Pin Functions

NAME	PIN			I/O	DESCRIPTION
	NO.				
	D (OPA1611)	D (OPA1612)	DRG (OPA1612)		
–IN	2	—	—	I	Inverting input
+IN	3	—	—	I	Noninverting input
–IN A	—	2	2	I	Inverting input, channel A
+IN A	—	3	3	I	Noninverting input, channel A
–IN B	—	6	6	I	Inverting input, channel B
+IN B	—	5	5	I	Noninverting input, channel B
NC	1, 5, 8	—	—	—	No internal connection
OUT	6	—	—	O	Output
OUT A	—	1	1	O	Output, channel A
OUT B	—	7	7	O	Output, channel B
V–	4	4	4	—	Negative (lowest) power supply
V+	7	8	8	—	Positive (highest) power supply

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6 Specifications

6.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)[1]

		MIN	MAX	UNIT
Supply voltage	$V_S = (V+) - (V-)$		40	V
Input voltage		$(V-) - 0.5$	$(V+) + 0.5$	V
Input current (all pins except power-supply pins)			±10	mA
Output short-circuit[2]		Continuous		
Operating temperature	(T_A)	−55	+125	°C
Junction temperature	(T_J)		200	°C

(1) Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under *Recommended Operating Conditions*. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
(2) Short-circuit to V_S / 2 (ground in symmetrical dual supply setups), one amplifier per package.

6.2 Handling Ratings

			MIN	MAX	UNIT
T_{stg}	Storage temperature range		−65	+150	°C
$V_{(ESD)}$	Electrostatic discharge	Human body model (HBM), per ANSI/ESDA/JEDEC JS-001, all pins[1]	−3000	3000	V
		Charged device model (CDM), per JEDEC specification JESD22-C101, all pins[2]	−1000	1000	
		Machine model (MM)	−200	200	

(1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.
(2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

6.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

	MIN	NOM	MAX	UNIT
Supply voltage (V+ − V−)	4.5 (±2.25)		36 (±18)	V
Specified temperature	−40		+85	°C

6.4 Electrical Characteristics: V_S = ±2.25 V to ±18 V

At T_A = +25°C and R_L = 2 kΩ, unless otherwise noted. V_{CM} = V_{OUT} = midsupply, unless otherwise noted.

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
AUDIO PERFORMANCE						
THD+N	Total harmonic distortion + noise	G = +1, f = 1 kHz, V_O = 3 V_{RMS}		0.000015%		
				−136		dB
IMD	Intermodulation distortion	SMPTE/DIN two-tone, 4:1 (60 Hz and 7 kHz), G = +1, V_O = 3 V_{RMS}		0.000015%		
				−136		dB
		DIM 30 (3-kHz square wave and 15-kHz sine wave), G = +1, V_O = 3 V_{RMS}		0.000012%		
				−138		dB
		CCIF twin-tone (19 kHz and 20 kHz), G = +1, V_O = 3 V_{RMS}		0.000008%		
				−142		dB
FREQUENCY RESPONSE						
GBW	Gain-bandwidth product	G = 100		80		MHz
		G = 1		40		MHz
SR	Slew rate	G = −1		27		V/µs
	Full-power bandwidth[1]	V_O = 1 V_{PP}		4		MHz
	Overload recovery time	G = −10		500		ns
	Channel separation (dual)	f = 1 kHz		−130		dB
NOISE						
	Input voltage noise	f = 20 Hz to 20 kHz		1.2		µV_{PP}
e_n	Input voltage noise density[2]	f = 10 Hz		2		nV/√Hz
		f = 100 Hz		1.5		nV/√Hz
		f = 1 kHz		1.1	1.5	nV/√Hz
I_n	Input current noise density	f = 10 Hz		3		pA/√Hz
		f = 1 kHz		1.7		pA/√Hz
OFFSET VOLTAGE						
V_{OS}	Input offset voltage	V_S = ±15 V		±100	±500	µV
dV_{OS}/dT	V_{OS} over temperature[2]	T_A = −40°C to +85°C		1	4	µV/°C
PSRR	Power-supply rejection ratio	V_S = ±2.25 V to ±18 V		0.1	1	µV/V
INPUT BIAS CURRENT						
I_B	Input bias current	V_{CM} = 0 V		±60	±250	nA
		VCM = 0 V, DRG package only		±60	±300	nA
	I_B over temperature[2]	T_A = −40°C to +85°C			350	nA
I_{OS}	Input offset current	V_{CM} = 0 V		±25	±175	nA
INPUT VOLTAGE RANGE						
V_{CM}	Common-mode voltage range		(V−) + 2		(V+) − 2	V
CMRR	Common-mode rejection ratio	(V−) + 2 V ≤ V_{CM} ≤ (V+) − 2 V	110	120		dB
INPUT IMPEDANCE						
	Differential			20k ‖ 8		Ω ‖ pF
	Common-mode			10^9 ‖ 2		Ω ‖ pF

(1) Full-power bandwidth = SR / (2π × V_P), where SR = slew rate.
(2) Specified by design and characterization.

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OPA1611, OPA1612

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Electrical Characteristics: V$_S$ = ±2.25 V to ±18 V (continued)

At T$_A$ = +25°C and R$_L$ = 2 kΩ, unless otherwise noted. V$_{CM}$ = V$_{OUT}$ = midsupply, unless otherwise noted.

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
OPEN-LOOP GAIN						
A$_{OL}$	Open-loop voltage gain	(V−) + 0.2 V ≤ V$_O$ ≤ (V+) − 0.2 V, R$_L$ = 10 kΩ	114	130		dB
		(V−) + 0.6 V ≤ V$_O$ ≤ (V+) − 0.6 V, R$_L$ = 2 kΩ	110	114		dB
OUTPUT						
V$_{OUT}$	Voltage output	R$_L$ = 10 kΩ, A$_{OL}$ ≥ 114 dB	(V−) + 0.2		(V+) − 0.2	V
		R$_L$ = 2 kΩ, A$_{OL}$ ≥ 110 dB	(V−) + 0.6		(V+) − 0.6	V
I$_{OUT}$	Output current			See Figure 27		mA
Z$_O$	Open-loop output impedance			See Figure 28		Ω
I$_{SC}$	Short-circuit current			+55		mA
				−62		mA
C$_{LOAD}$	Capacitive load drive			See Typical Characteristics		pF
POWER SUPPLY						
V$_S$	Specified voltage		±2.25		±18	V
I$_Q$	Quiescent current (per channel)	I$_{OUT}$ = 0 A		3.6	4.5	mA
	I$_Q$ over Temperature [3]	T$_A$ = −40°C to +85°C			5.5	mA
TEMPERATURE RANGE						
	Specified range		−40		+85	°C
	Operating range		−55		+125	°C
θ$_{JA}$	Thermal resistance, SOIC-8			150		°C/W

(3) Specified by design and characterization.

Product Folder Links: OPA1611 OPA1612

6.5 Typical Characteristics

At T_A = +25°C, V_S = ±15 V, and R_L = 2 kΩ, unless otherwise noted.

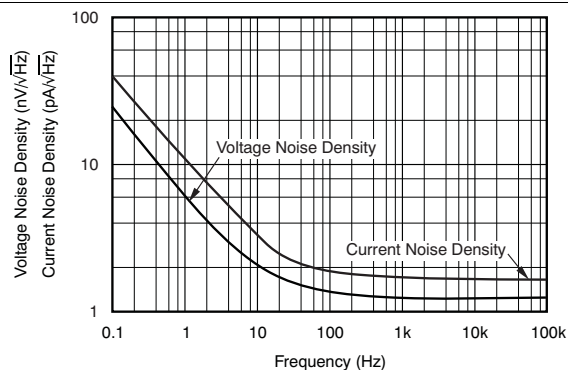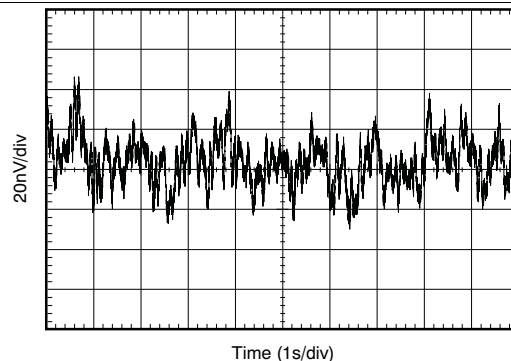**Figure 1. Input Voltage Noise Density and Input Current Noise Density vs Frequency**
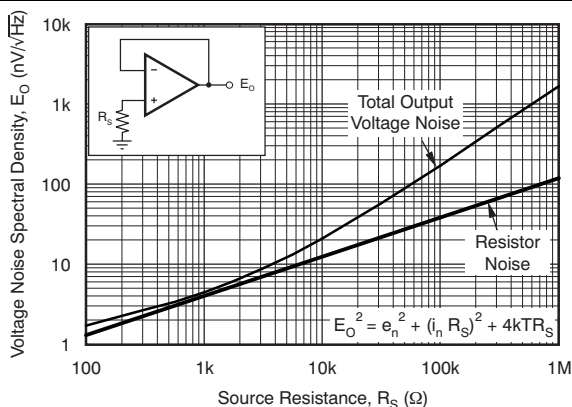

Figure 2. 0.1-Hz to 10-Hz Noise

$$E_O^2 = e_n^2 + (i_n R_S)^2 + 4kTR_S$$
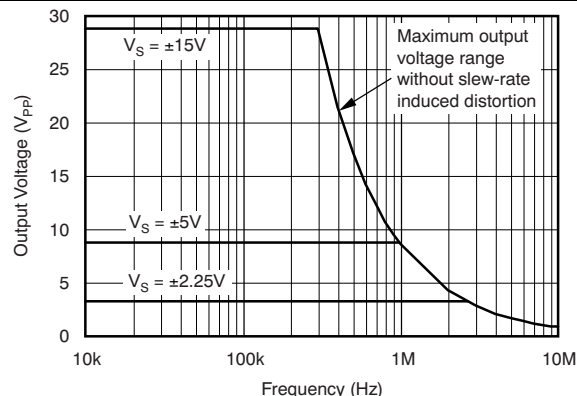
Figure 3. Voltage Noise vs Source Resistance

Figure 4. Maximum Output Voltage vs Frequency
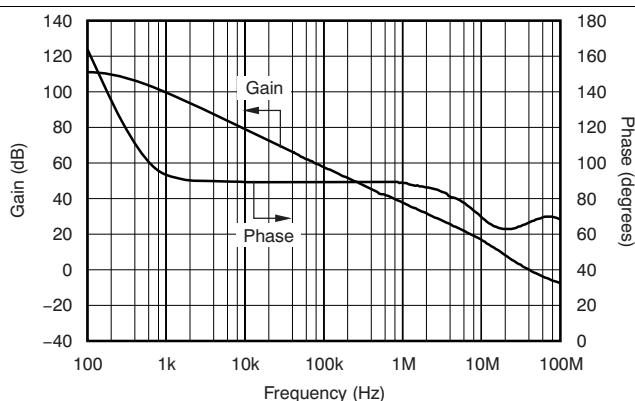
Figure 5. Gain and Phase vs Frequency
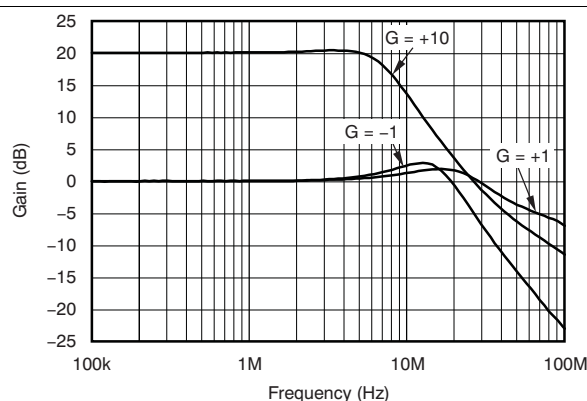
Figure 6. Closed-Loop Gain vs Frequency

Typical Characteristics (continued)

At T_A = +25°C, V_S = ±15 V, and R_L = 2 kΩ, unless otherwise noted.
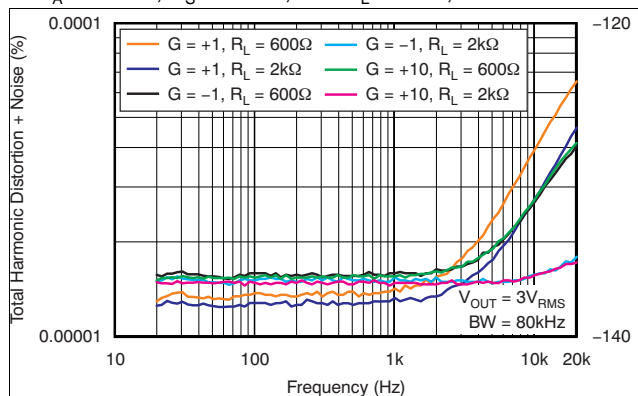
Figure 7. THD+N Ratio vs Frequency
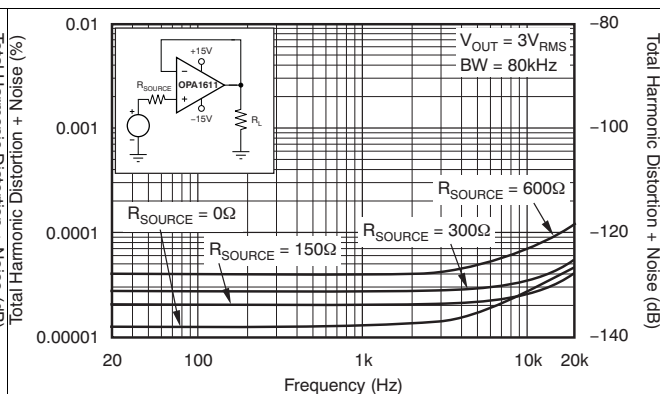
Figure 8. THD+N Ratio vs Frequency
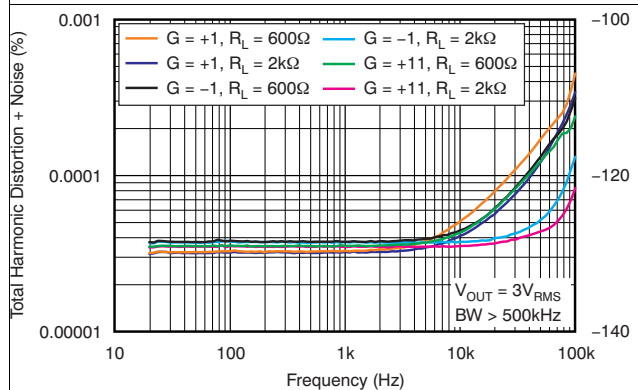
Figure 9. THD+N Ratio vs Frequency
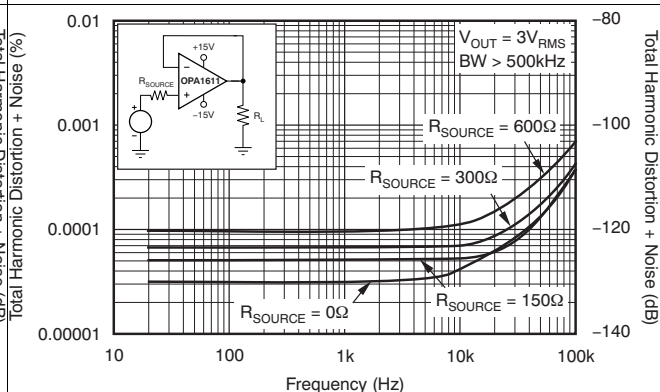
Figure 10. THD+N Ratio vs Frequency
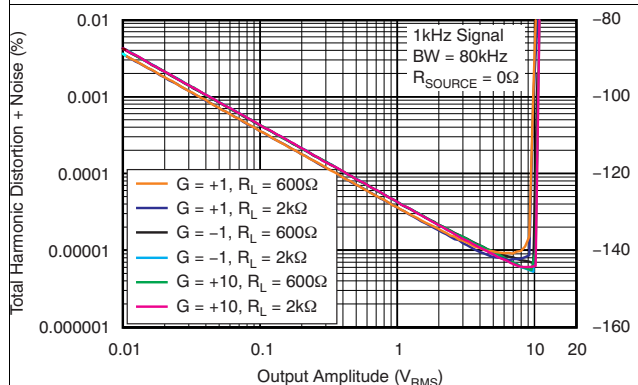
Figure 11. THD+N Ratio vs Output Amplitude
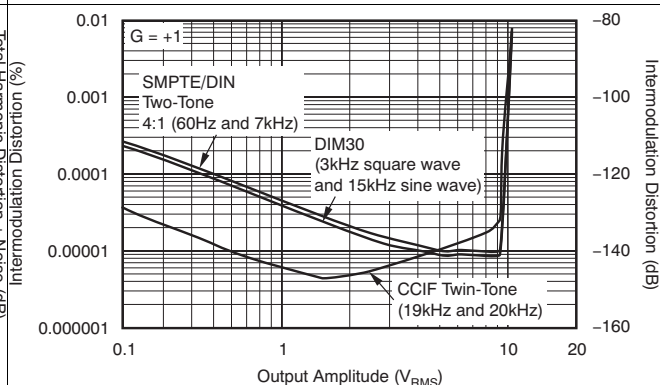
Figure 12. Intermodulation Distortion vs Output Amplitude

Product Folder Links: *OPA1611 OPA1612*

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Typical Characteristics (continued)

At T_A = +25°C, V_S = ±15 V, and R_L = 2 kΩ, unless otherwise noted.
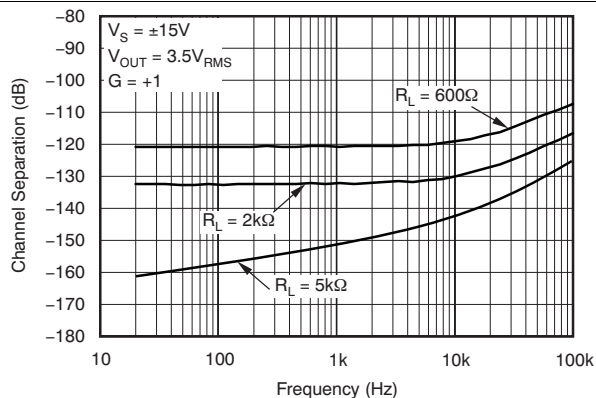
Figure 13. Channel Separation vs Frequency
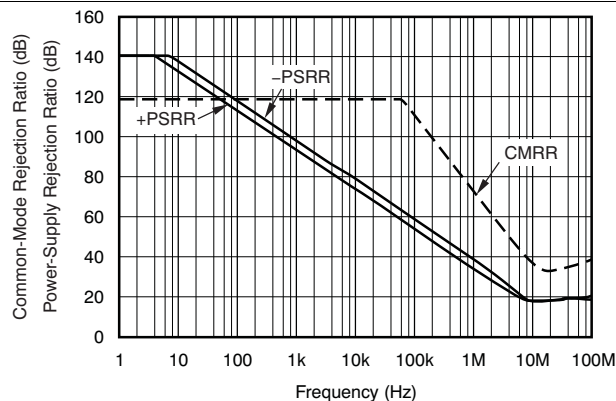
**Figure 14. CMRR and PSRR vs Frequency
(Referred to Input)**
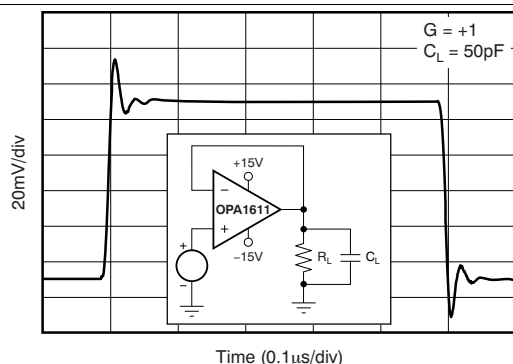
Figure 15. Small-Signal Step Response (100 mV)
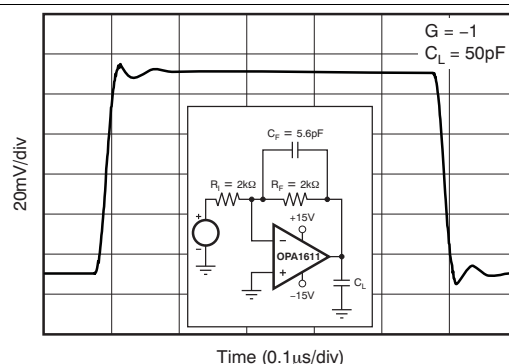
Figure 16. Small-Signal Step Response (100 mV)
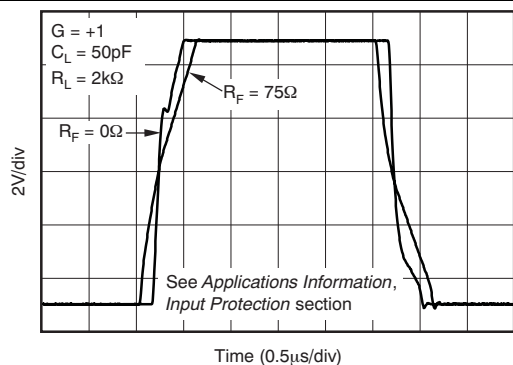
Figure 17. Large-Signal Step Response
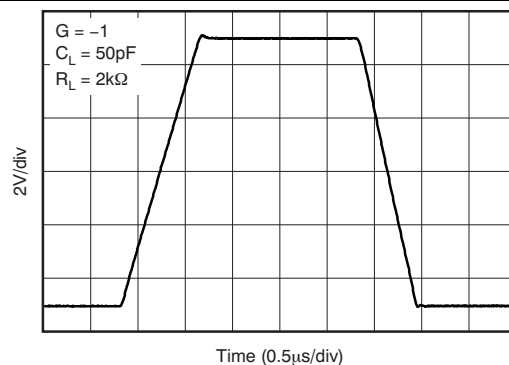
Figure 18. Large-Signal Step Response

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INSTRUMENTS

OPA1611, OPA1612

Typical Characteristics (continued)

At T_A = +25°C, V_S = ±15 V, and R_L = 2 kΩ, unless otherwise noted.
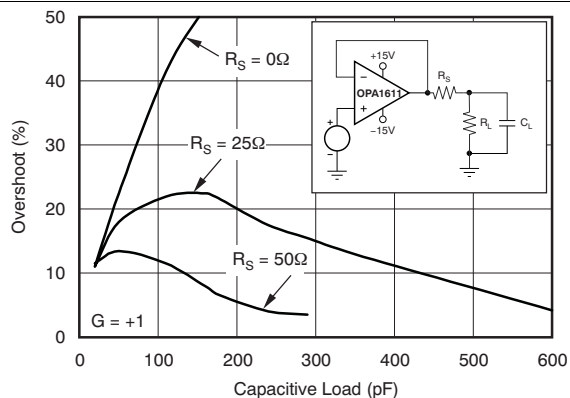
Figure 19. Small-Signal Overshoot vs Capacitive Load
(100-mV Output Step)
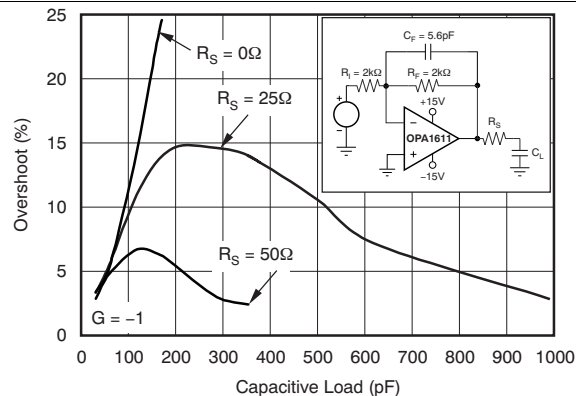
Figure 20. Small-Signal Overshoot vs Capacitive Load
(100-mV Output Step)
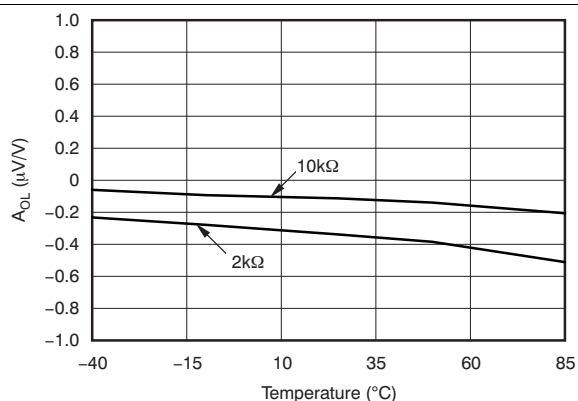
Figure 21. Open-Loop Gain vs Temperature
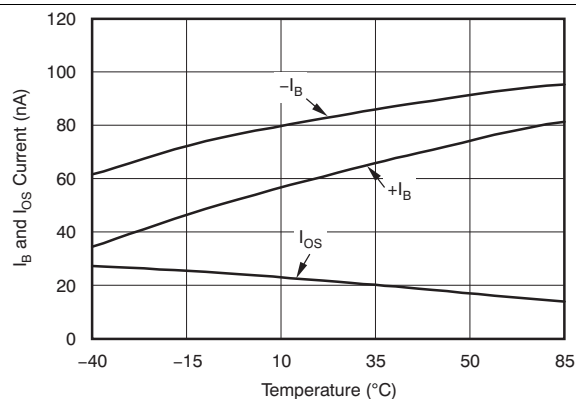
Figure 22. I_B and I_{OS} vs Temperature
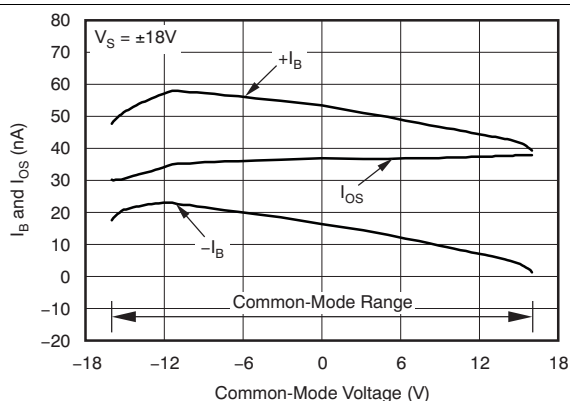
Figure 23. I_B and I_{OS} vs Common-Mode Voltage
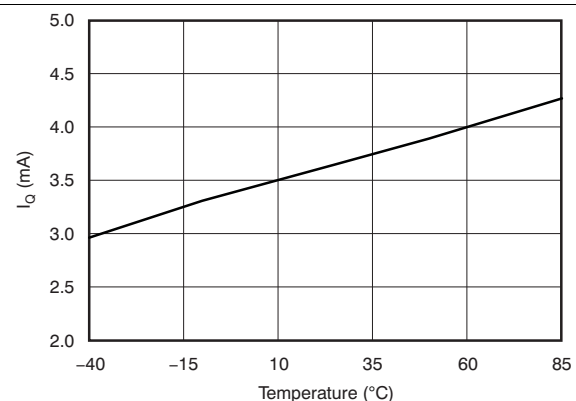
Figure 24. Quiescent Current vs Temperature

Product Folder Links: *OPA1611 OPA1612*

Typical Characteristics (continued)

At T_A = +25°C, V_S = ±15 V, and R_L = 2 kΩ, unless otherwise noted.
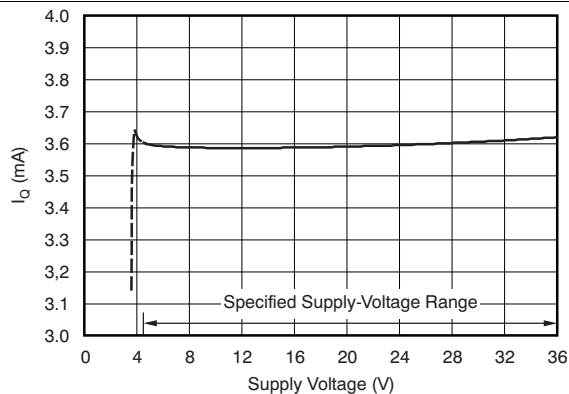
Figure 25. Quiescent Current vs Supply Voltage
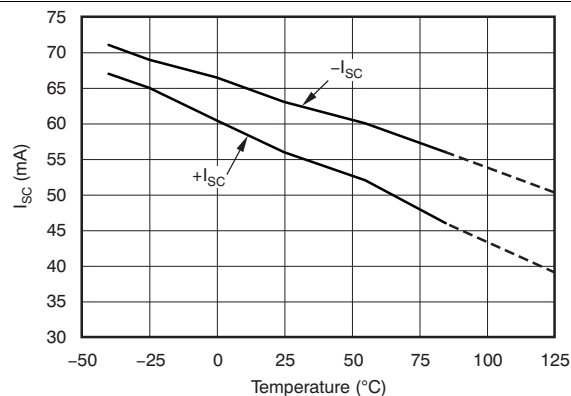
Figure 26. Short-Circuit Current vs Temperature
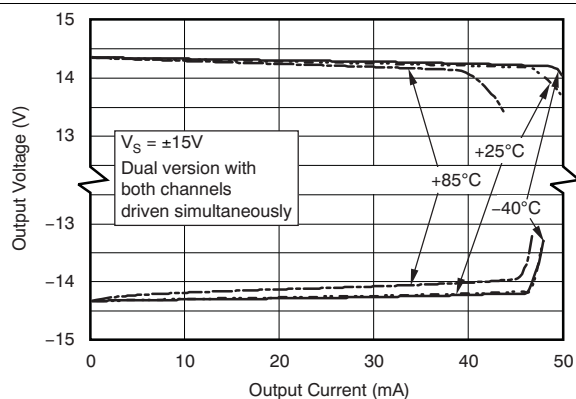
Figure 27. Output Voltage vs Output Current
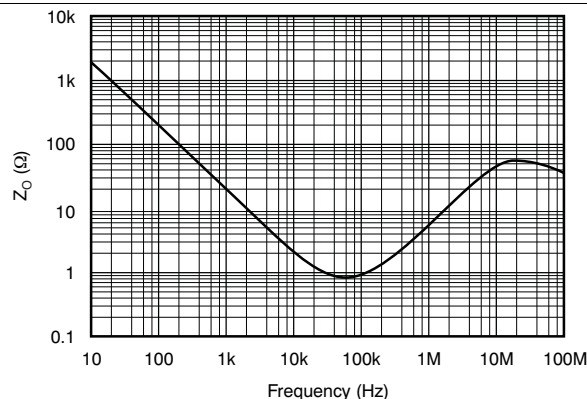
Figure 28. Open-Loop Output Impedance vs Frequency

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7 Detailed Description

7.1 Overview

The OPA161x family of bipolar-input operational amplifiers achieve very low 1.1-nV/√Hz noise density with an ultralow distortion of 0.000015% at 1 kHz. The rail-to-rail output swing, within 600 mV with a 2-kΩ load, increases headroom and maximizes dynamic range. These devices also have a high output drive capability of ±40 mA. The wide supply range of ±2.25 V to ±18 V, on only 3.6 mA of supply current per channel, makes them applicable to both 5V systems and 36V audio applications. The OPA1611 and OPA1612 op amps are unity-gain stable and provide excellent dynamic behavior over a wide range of load conditions.

7.2 Functional Block Diagram
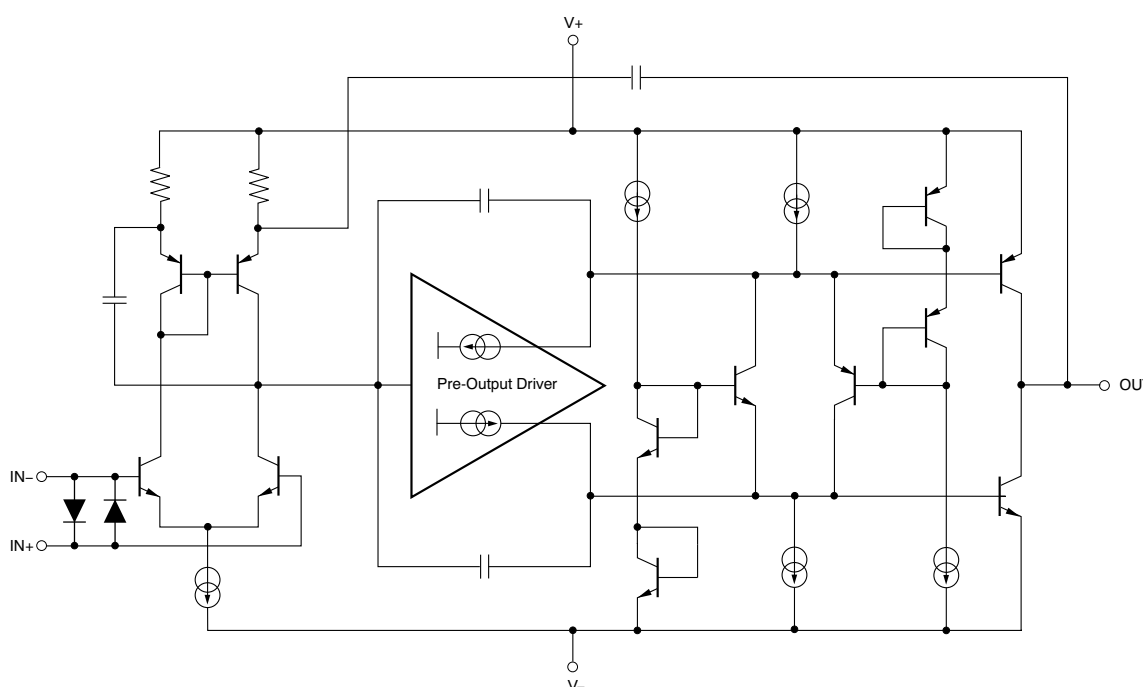
Figure 29. OPA1611 Simplified Schematic

7.3 Feature Description

7.3.1 Power Dissipation

The OPA1611 and OPA1612 series op amps are capable of driving 2-kΩ loads with a power-supply voltage up to ±18 V. Internal power dissipation increases when operating at high supply voltages. Copper leadframe construction used in the OPA1611 and OPA1612 series op amps improves heat dissipation compared to conventional materials. Circuit board layout can also help minimize junction temperature rise. Wide copper traces help dissipate the heat by acting as an additional heat sink. Temperature rise can be further minimized by soldering the devices to the circuit board rather than using a socket.

7.3.2 Electrical Overstress

Designers often ask questions about the capability of an operational amplifier to withstand electrical overstress. These questions tend to focus on the device inputs, but may involve the supply voltage pins or even the output pin. Each of these different pin functions have electrical stress limits determined by the voltage breakdown characteristics of the particular semiconductor fabrication process and specific circuits connected to the pin. Additionally, internal electrostatic discharge (ESD) protection is built into these circuits to protect them from accidental ESD events both before and during product assembly.

Product Folder Links: *OPA1611 OPA1612*

Feature Description (continued)

Having a good understanding of this basic ESD circuitry and its relevance to an electrical overstress event is helpful. Figure 30 shows the ESD circuits contained in the OPA161x series (indicated by the dashed line area). The ESD protection circuitry involves several current-steering diodes connected from the input and output pins and routed back to the internal power-supply lines, where they meet at an absorption device internal to the operational amplifier. This protection circuitry is intended to remain inactive during normal circuit operation.
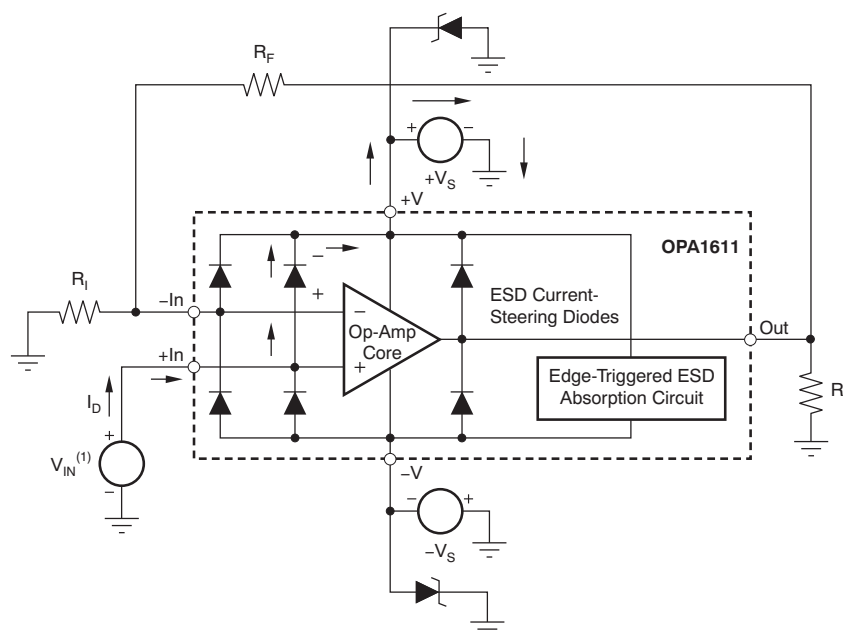
(1) V_{IN} = +V_S + 500 mV.

Figure 30. Equivalent Internal ESD Circuitry and its Relation to a Typical Circuit Application

An ESD event produces a short duration, high-voltage pulse that is transformed into a short duration, high-current pulse when discharged through a semiconductor device. The ESD protection circuits are designed to provide a current path around the operational amplifier core to prevent damage to the core. The energy absorbed by the protection circuitry is then dissipated as heat.

When an ESD voltage develops across two or more of the amplifier device pins, current flows through one or more of the steering diodes. Depending on the path that the current takes, the absorption device may activate. The absorption device internal to the OPA1611 triggers when a fast ESD voltage pulse is impressed across the supply pins. Once triggered, the absorption device quickly activates and clamps the ESD pulse to a safe voltage level.

When the operational amplifier connects into a circuit such as the one Figure 30 shows, the ESD protection components are intended to remain inactive and not become involved in the application circuit operation. However, circumstances may arise where an applied voltage exceeds the operating voltage range of a given pin. If this condition occurs, some of the internal ESD protection circuits may possibly be biased on, and conduct current. Any such current flow occurs through steering diode paths and rarely involves the absorption device.

Figure 30 shows a specific example where the input voltage, V_{IN}, exceeds the positive supply voltage (+V_S) by 500 mV or more. Much of what happens in the circuit depends on the supply characteristics. If +V_S can sink the current, one of the upper input steering diodes conducts and directs current to +V_S. Excessively high current levels can flow with increasingly higher V_{IN}. As a result, the datasheet specifications recommend that applications limit the input current to 10 mA.

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Feature Description (continued)

If the supply is not capable of sinking the current, V_{IN} may begin sourcing current to the operational amplifier, and then take over as the source of positive supply voltage. The danger in this case is that the voltage can rise to levels that exceed the operational amplifier absolute maximum ratings. In extreme but rare cases, the absorption device triggers on while $+V_S$ and $-V_S$ are applied. If this event happens, a direct current path is established between the $+V_S$ and $-V_S$ supplies. The power dissipation of the absorption device is quickly exceeded, and the extreme internal heating destroys the operational amplifier.

Another common question involves what happens to the amplifier if an input signal is applied to the input while the power supplies $+V_S$ or $-V_S$ are at 0 V. Again, the result depends on the supply characteristic while at 0 V, or at a level below the input signal amplitude. If the supplies appear as high impedance, then the operational amplifier supply current may be supplied by the input source via the current steering diodes. This state is not a normal bias condition; the amplifier most likely does not operate normally. If the supplies are low impedance, then the current through the steering diodes can become quite high. The current level depends on the ability of the input source to deliver current, and any resistance in the input path.

If there is an uncertainty about the ability of the supply to absorb this current, external zener diodes may be added to the supply pins; see Figure 30. The zener voltage must be selected such that the diode does not turn on during normal operation. However, the zener diode voltage must be low enough so that the zener diode conducts if the supply pin begins to rise above the safe operating supply voltage level.

7.3.3 Operating Voltage

The OPA161x series op amps operate from ±2.25-V to ±18-V supplies while maintaining excellent performance. The OPA161x series can operate with as little as +4.5 V between the supplies and with up to +36 V between the supplies. However, some applications do not require equal positive and negative output voltage swing. With the OPA161x series, power-supply voltages do not need to be equal. For example, the positive supply could be set to +25 V with the negative supply at –5 V.

In all cases, the common-mode voltage must be maintained within the specified range. In addition, key parameters are assured over the specified temperature range of $T_A = -40°C$ to $+85°C$. Parameters that vary with operating voltage or temperature are shown in the Typical Characteristics.

7.3.4 Input Protection

The input terminals of the OPA1611 and the OPA1612 are protected from excessive differential voltage with back-to-back diodes, as Figure 31 shows. In most circuit applications, the input protection circuitry has no consequence. However, in low-gain or G = +1 circuits, fast ramping input signals can forward bias these diodes because the output of the amplifier cannot respond rapidly enough to the input ramp. This effect is illustrated in Figure 17 of the Typical Characteristics. If the input signal is fast enough to create this forward bias condition, the input signal current must be limited to 10 mA or less. If the input signal current is not inherently limited, an input series resistor (R_I) or a feedback resistor (R_F) can be used to limit the signal input current. This input series resistor degrades the low-noise performance of the OPA1611 and is examined in the *Noise Performance* section. Figure 31 shows an example configuration when both current-limiting input and feedback resistors are used.
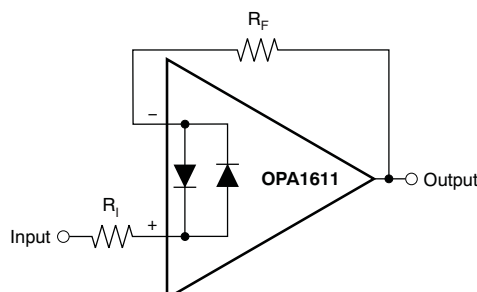
Figure 31. Pulsed Operation

TEXAS INSTRUMENTS

OPA1611, OPA1612

8 Application and Implementation

8.1 Application Information

The OPA1611 and OPA1612 are unity-gain stable, precision op amps with very low noise; these devices are also free from output phase reversal. Applications with noisy or high-impedance power supplies require decoupling capacitors close to the device power-supply pins. In most cases, 0.1-µF capacitors are adequate.

8.2 Noise Performance

Figure 32 shows the total circuit noise for varying source impedances with the op amp in a unity-gain configuration (no feedback resistor network, and therefore no additional noise contributions).

The OPA1611 (GBW = 40 MHz, G = +1) is shown with total circuit noise calculated. The op amp itself contributes both a voltage noise component and a current noise component. The voltage noise is commonly modeled as a time-varying component of the offset voltage. The current noise is modeled as the time-varying component of the input bias current and reacts with the source resistance to create a voltage component of noise. Therefore, the lowest noise op amp for a given application depends on the source impedance. For low source impedance, current noise is negligible, and voltage noise generally dominates. The low voltage noise of the OPA161x series op amps makes them a good choice for use in applications where the source impedance is less than 1 kΩ.

8.2.1 Detailed Design Procedure

The equation in Figure 32 shows the calculation of the total circuit noise, with these parameters:
- e_n = voltage noise
- I_n = current noise
- R_S = source impedance
- k = Boltzmann's constant = 1.38×10^{-23} J/K
- T = temperature in degrees Kelvin (K)

8.2.2 Application Curve

Figure 32. Noise Performance of the OPA1611 In Unity-Gain Buffer Configuration
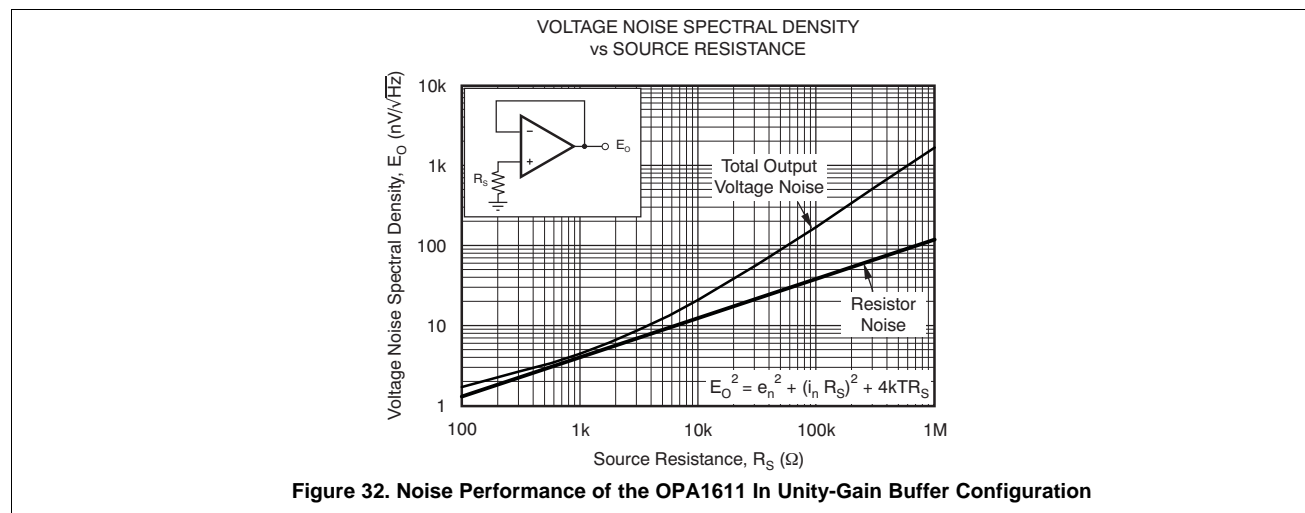
8.2.3 Basic Noise Calculations

Design of low-noise op amp circuits requires careful consideration of a variety of possible noise contributors: noise from the signal source, noise generated in the op amp, and noise from the feedback network resistors. The total noise of the circuit is the root-sum-square combination of all noise components.

The resistive portion of the source impedance produces thermal noise proportional to the square root of the resistance. Figure 32 plots this function. The source impedance is usually fixed; consequently, select the op amp and the feedback resistors to minimize the respective contributions to the total noise.

Product Folder Links: *OPA1611 OPA1612*

OPA1611, OPA1612

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Noise Performance (continued)

Figure 33 shows both inverting and noninverting op amp circuit configurations with gain. In circuit configurations with gain, the feedback network resistors also contribute noise.

The current noise of the op amp reacts with the feedback resistors to create additional noise components. The feedback resistor values can generally be chosen to make these noise sources negligible. The equations for total noise are shown for both configurations.

Noise in Noninverting Gain Configuration
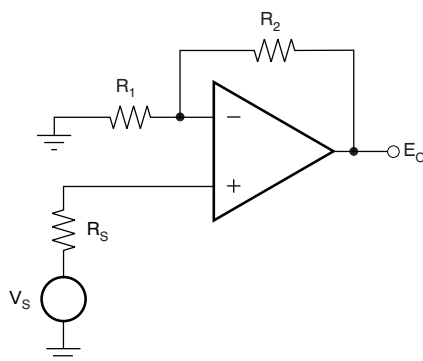
Noise at the output:

$$E_O{}^2 = \left(1 + \frac{R_2}{R_1}\right)^2 e_n{}^2 + e_1{}^2 + e_2{}^2 + (i_n R_2)^2 + e_S{}^2 + (i_n R_S)^2 \left(1 + \frac{R_2}{R_1}\right)^2$$

Where $e_S = \sqrt{4kTR_S} \times \left(1 + \frac{R_2}{R_1}\right)$ = thermal noise of R_S

$e_1 = \sqrt{4kTR_1} \times \left(\frac{R_2}{R_1}\right)$ = thermal noise of R_1

$e_2 = \sqrt{4kTR_2}$ = thermal noise of R_2

Noise in Inverting Gain Configuration
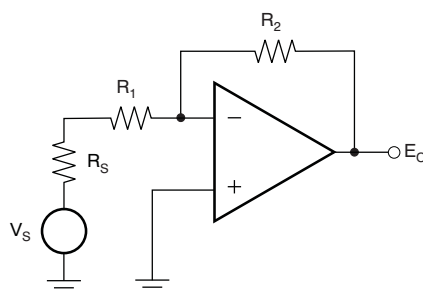
Noise at the output:

$$E_O{}^2 = \left(1 + \frac{R_2}{R_1 + R_S}\right)^2 e_n{}^2 + e_1{}^2 + e_2{}^2 + (i_n R_2)^2 + e_S{}^2$$

Where $e_S = \sqrt{4kTR_S} \times \left(\frac{R_2}{R_1 + R_S}\right)$ = thermal noise of R_S

$e_1 = \sqrt{4kTR_1} \times \left(\frac{R_2}{R_1 + R_S}\right)$ = thermal noise of R_1

$e_2 = \sqrt{4kTR_2}$ = thermal noise of R_2

For the OPA161x series op amps at 1 kHz, $e_n = 1.1$ nV/$\sqrt{Hz}$ and $i_n = 1.7$ pA/$\sqrt{Hz}$.

Figure 33. Noise Calculation in Gain Configurations

Product Folder Links: *OPA1611 OPA1612*

8.3 Total Harmonic Distortion Measurements

The OPA161x series op amps have excellent distortion characteristics. THD + noise is below 0.00008% (G = +1, V_O = 3 V_{RMS}, BW = 80 kHz) throughout the audio frequency range, 20 Hz to 20 kHz, with a 2-kΩ load (see Figure 7 for characteristic performance).

The distortion produced by OPA1611 series op amps is below the measurement limit of many commercially available distortion analyzers. However, a special test circuit (such as Figure 34 shows) can be used to extend the measurement capabilities.

Op amp distortion can be considered an internal error source that can be referred to the input. Figure 34 shows a circuit that causes the op amp distortion to be 101 times (or approximately 40 dB) greater than that normally produced by the op amp. The addition of R_3 to the otherwise standard noninverting amplifier configuration alters the feedback factor or noise gain of the circuit. The closed-loop gain is unchanged, but the feedback available for error correction is reduced by a factor of 101, thus extending the resolution by 101. Note that the input signal and load applied to the op amp are the same as with conventional feedback without R_3. Keep the value of R_3 small to minimize its effect on the distortion measurements.

Validity of this technique can be verified by duplicating measurements at high gain and/or high frequency where the distortion is within the measurement capability of the test equipment. Measurements for this data sheet were made with an audio precision system two distortion and noise analyzer, which greatly simplifies such repetitive measurements. The measurement technique can, however, be performed with manual distortion measurement instruments.

Signal Gain = $1 + \dfrac{R_2}{R_1}$

Distortion Gain = $1 + \dfrac{R_2}{R_1 \parallel R_3}$

SIG. GAIN	DIST. GAIN	R_1	R_2	R_3
1	101	∞	1kΩ	10Ω
–1	101	4.99kΩ	4.99kΩ	49.9Ω
+10	110	549Ω	4.99kΩ	49.9Ω
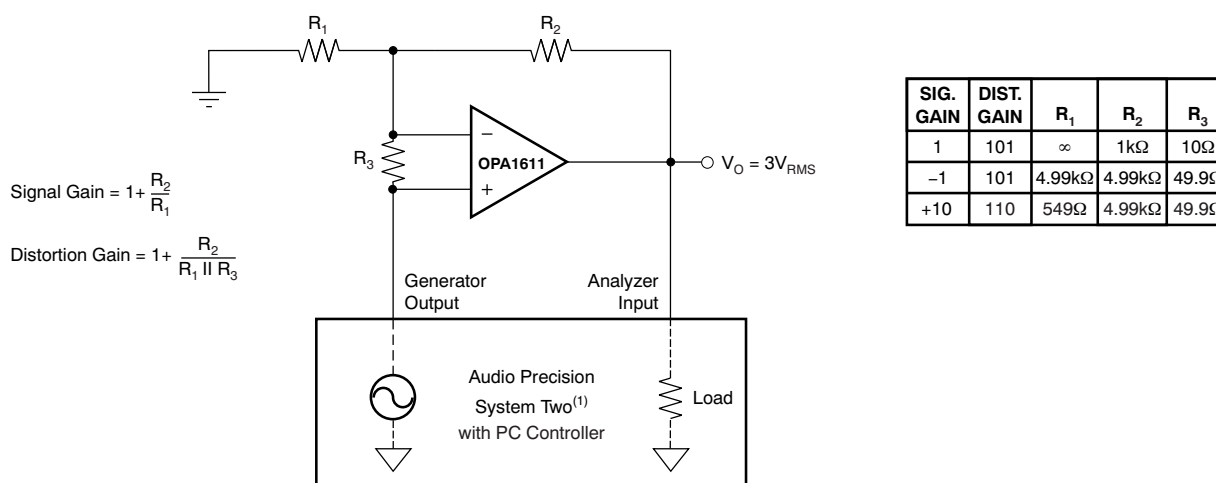
(1) For measurement bandwidth, see Figure 7 through Figure 12.

Figure 34. Distortion Test Circuit

8.4 Capacitive Loads

The dynamic characteristics of the OPA1611 and OPA1612 have been optimized for commonly encountered gains, loads, and operating conditions. The combination of low closed-loop gain and high capacitive loads decreases the phase margin of the amplifier and can lead to gain peaking or oscillations. As a result, heavier capacitive loads must be isolated from the output. The simplest way to achieve this isolation is to add a small resistor (R_S equal to 50 Ω, for example) in series with the output.

This small series resistor also prevents excess power dissipation if the output of the device becomes shorted. Figure 19 and Figure 20 illustrate graphs of *Small-Signal Overshoot vs Capacitive Load* for several values of R_S. Also, refer to Applications Bulletin AB-028, *Feedback Plots Define Op Amp AC Performance* (SBOA015), available for download from the TI web site, for details of analysis techniques and application circuits.

8.5 Application Circuit

Figure 35 shows how to use the OPA1611 as an amplifier for professional audio headphones. The circuit shows the left side stereo channel. An identical circuit is used to drive the right side stereo channel.
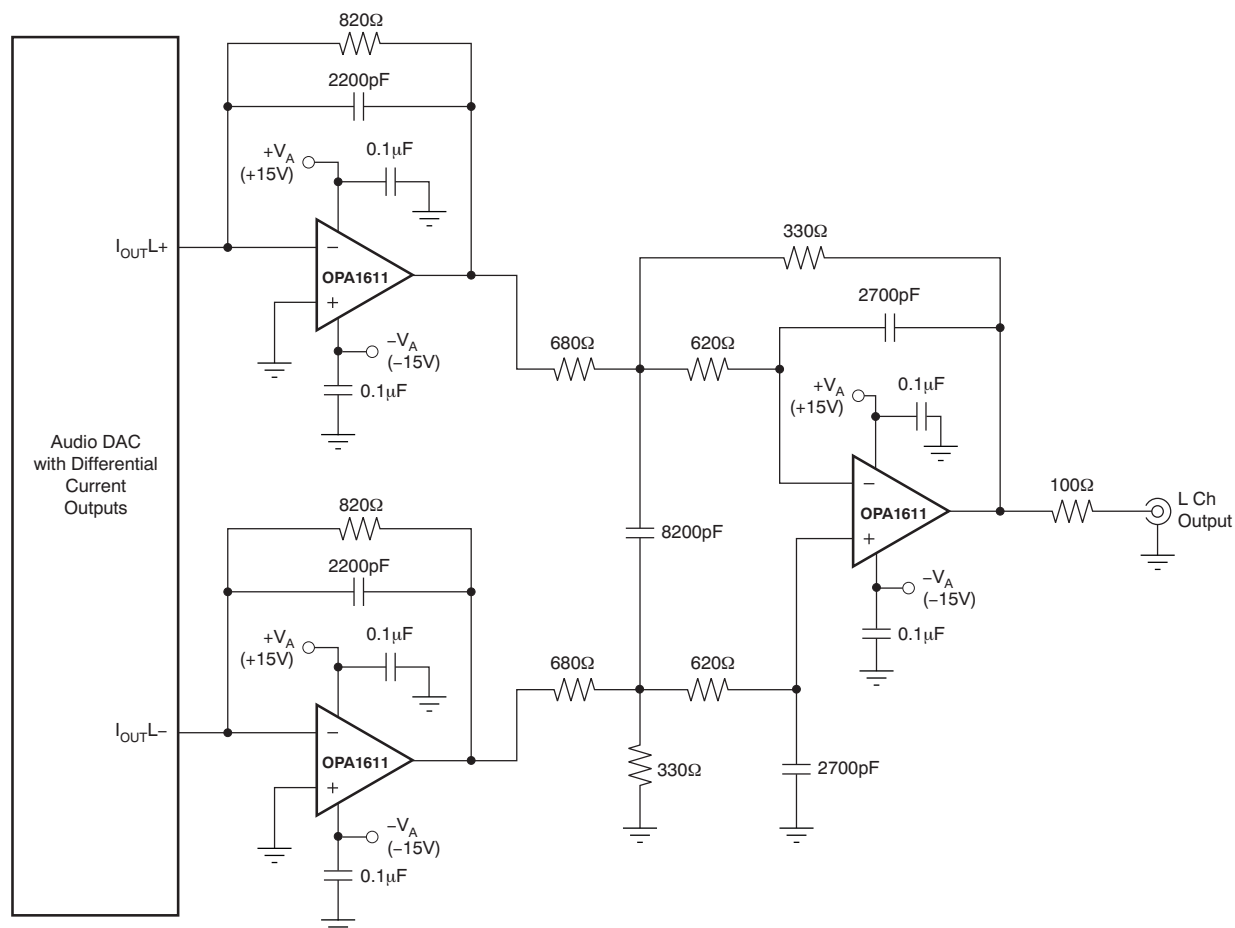
Figure 35. Audio DAC Post Filter (I/V Converter and Low-Pass Filter)

9 Power-Supply Recommendations

The OPA161x is specified for operation from 4.5 V to 36 V (±2.25 V to ±18 V); many specifications apply from –40°C to +85°C. Parameters that can exhibit significant variance with regard to operating voltage or temperature are presented in the *Typical Characteristics* section.

CAUTION

Supply voltages larger than 40 V can permanently damage the device; see the *Absolute Maximum Ratings*.

Place 0.1-µF bypass capacitors close to the power-supply pins to reduce errors coupling in from noisy or high-impedance power supplies. For more detailed information on bypass capacitor placement, refer to the *Typical Characteristics* section.

10 Layout

10.1 Layout Guidelines

For best operational performance of the device, use good printed circuit board (PCB) layout practices, including:

- Noise can propagate into analog circuitry through the power pins of the circuit as a whole and the op amp itself. Bypass capacitors are used to reduce the coupled noise by providing low-impedance power sources local to the analog circuitry.
  - Connect low-ESR, 0.1-µF ceramic bypass capacitors between each supply pin and ground, placed as close to the device as possible. A single bypass capacitor from V+ to ground is applicable for single-supply applications.
- Separate grounding for analog and digital portions of the circuitry is one of the simplest and most-effective methods of noise suppression. One or more layers on multilayer PCBs are usually devoted to ground planes. A ground plane helps distribute heat and reduces EMI noise pickup. Make sure to physically separate digital and analog grounds while paying attention to the flow of the ground current. For more detailed information, refer to the application report *Circuit Board Layout Techniques* (SLOA089).
- In order to reduce parasitic coupling, run the input traces as far away from the supply or output traces as possible. If these traces cannot be keep them separate, crossing the sensitive trace perpendicular as opposed to in parallel with the noisy trace is the preferred method.
- Place the external components as close to the device as possible. As shown in Figure 36, keeping RF and RG close to the inverting input minimizes parasitic capacitance.
- Keep the length of input traces as short as possible. Always remember that the input traces are the most sensitive part of the circuit.
- Consider a driven, low-impedance guard ring around the critical traces. A guard ring can significantly reduce leakage currents from nearby traces that are at different potentials.

10.2 Layout Example

(Schematic Representation)
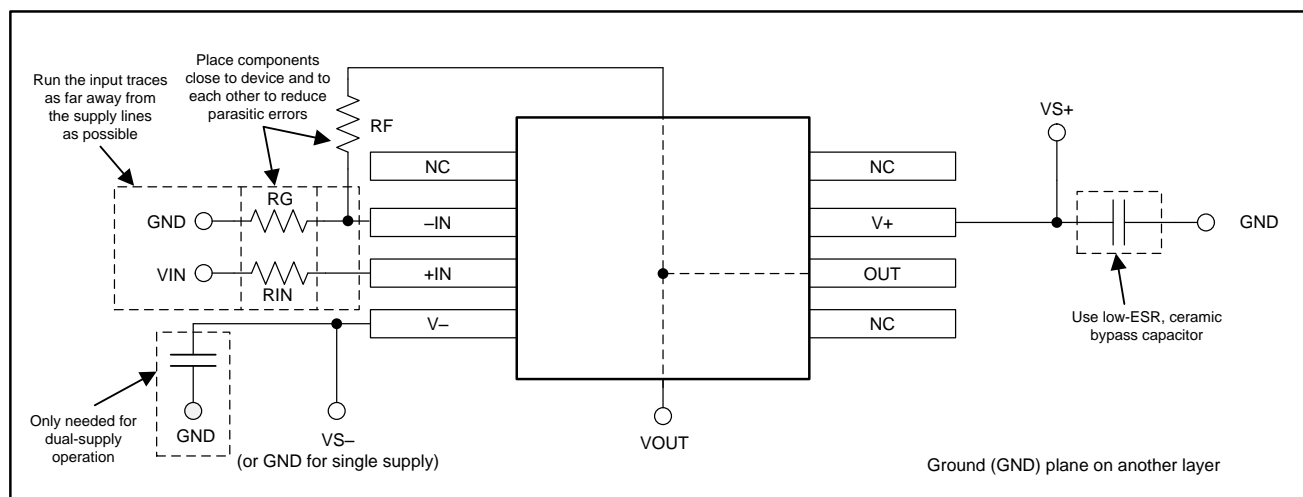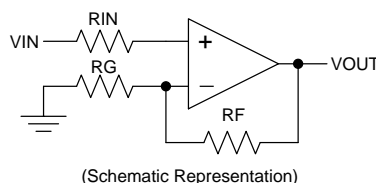
Figure 36. Operational Amplifier Board Layout for a Noninverting Configuration

Distributor of Texas Instruments: Excellent Integrated System Limited
Datasheet of OPA1611AID - IC OPAMP AUDIO 80MHZ 8SOIC
Contact us: sales@integrated-circuit.com Website: www.integrated-circuit.com

TEXAS INSTRUMENTS

OPA1611, **OPA1612**

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11 Device and Documentation Support

11.1 Documentation Support

11.1.1 Related Documentation

For related documentation see the following:
- *Feedback Plots Define Op Amp AC Performance* , SBOA015
- *Circuit Board Layout Techniques*, SLOA089

11.2 Related Links

The table below lists quick access links. Categories include technical documents, support and community resources, tools and software, and quick access to sample or buy.

Table 1. Related Links

PARTS	PRODUCT FOLDER	SAMPLE & BUY	TECHNICAL DOCUMENTS	TOOLS & SOFTWARE	SUPPORT & COMMUNITY
OPA1611	Click here	Click here	Click here	Click here	Click here
OPA1612	Click here	Click here	Click here	Click here	Click here

11.3 Trademarks

SoundPlus is a trademark of Texas Instruments, Inc.
All other trademarks are the property of their respective owners.

11.4 Electrostatic Discharge Caution

These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

11.5 Glossary

SLYZ022 — *TI Glossary*.

This glossary lists and explains terms, acronyms, and definitions.

12 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

PACKAGE OPTION ADDENDUM

www.ti.com   29-Aug-2014

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
OPA1611AID	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 85	OPA 1611A	Samples
OPA1611AIDR	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 85	OPA 1611A	Samples
OPA1612AID	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 85	OPA 1612A	Samples
OPA1612AIDR	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 85	OPA 1612A	Samples
OPA1612AIDRGR	ACTIVE	SON	DRG	8	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 85	OVII	Samples
OPA1612AIDRGT	ACTIVE	SON	DRG	8	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 85	OVII	Samples

(1) The marketing status values are defined as follows:
ACTIVE: Product device recommended for new designs.
LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.
NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.
PREVIEW: Device has been announced but is not in production. Samples may or may not be available.
OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.
TBD: The Pb-Free/Green conversion plan has not been defined.
Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.
Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.
Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

PACKAGE OPTION ADDENDUM

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29-Aug-2014

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[6] Lead/Ball Finish - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

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In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

PACKAGE OPTION ADDENDUM

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PACKAGE MATERIALS INFORMATION

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4-Sep-2014

TAPE AND REEL INFORMATION

REEL DIMENSIONS

TAPE DIMENSIONS

A0	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers
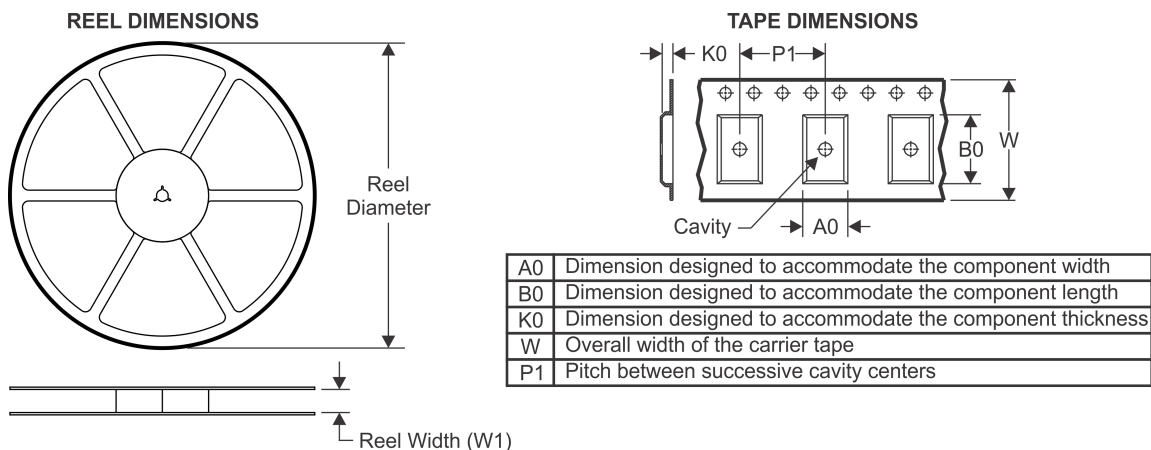
QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE
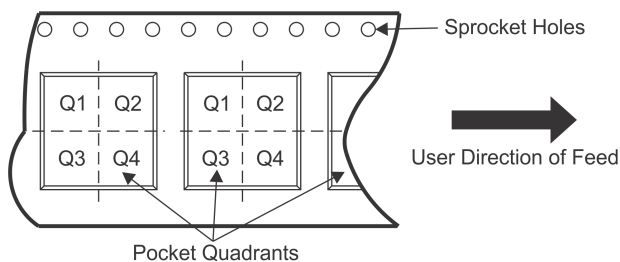
*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
OPA1611AIDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
OPA1612AIDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
OPA1612AIDRGR	SON	DRG	8	3000	330.0	12.4	3.3	3.3	1.1	8.0	12.0	Q2
OPA1612AIDRGT	SON	DRG	8	250	180.0	12.4	3.3	3.3	1.1	8.0	12.0	Q2

TEXAS INSTRUMENTS

PACKAGE MATERIALS INFORMATION

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4-Sep-2014

TAPE AND REEL BOX DIMENSIONS

*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
OPA1611AIDR	SOIC	D	8	2500	367.0	367.0	35.0
OPA1612AIDR	SOIC	D	8	2500	367.0	367.0	35.0
OPA1612AIDRGR	SON	DRG	8	3000	367.0	367.0	35.0
OPA1612AIDRGT	SON	DRG	8	250	210.0	185.0	35.0

MECHANICAL DATA

DRG (S−PWSON−N8)   PLASTIC SMALL OUTLINE NO−LEAD

Pin 1 Index Area
Top and Bottom

Exposed Thermal Die Pad

Bottom View

4205379/C 12/10
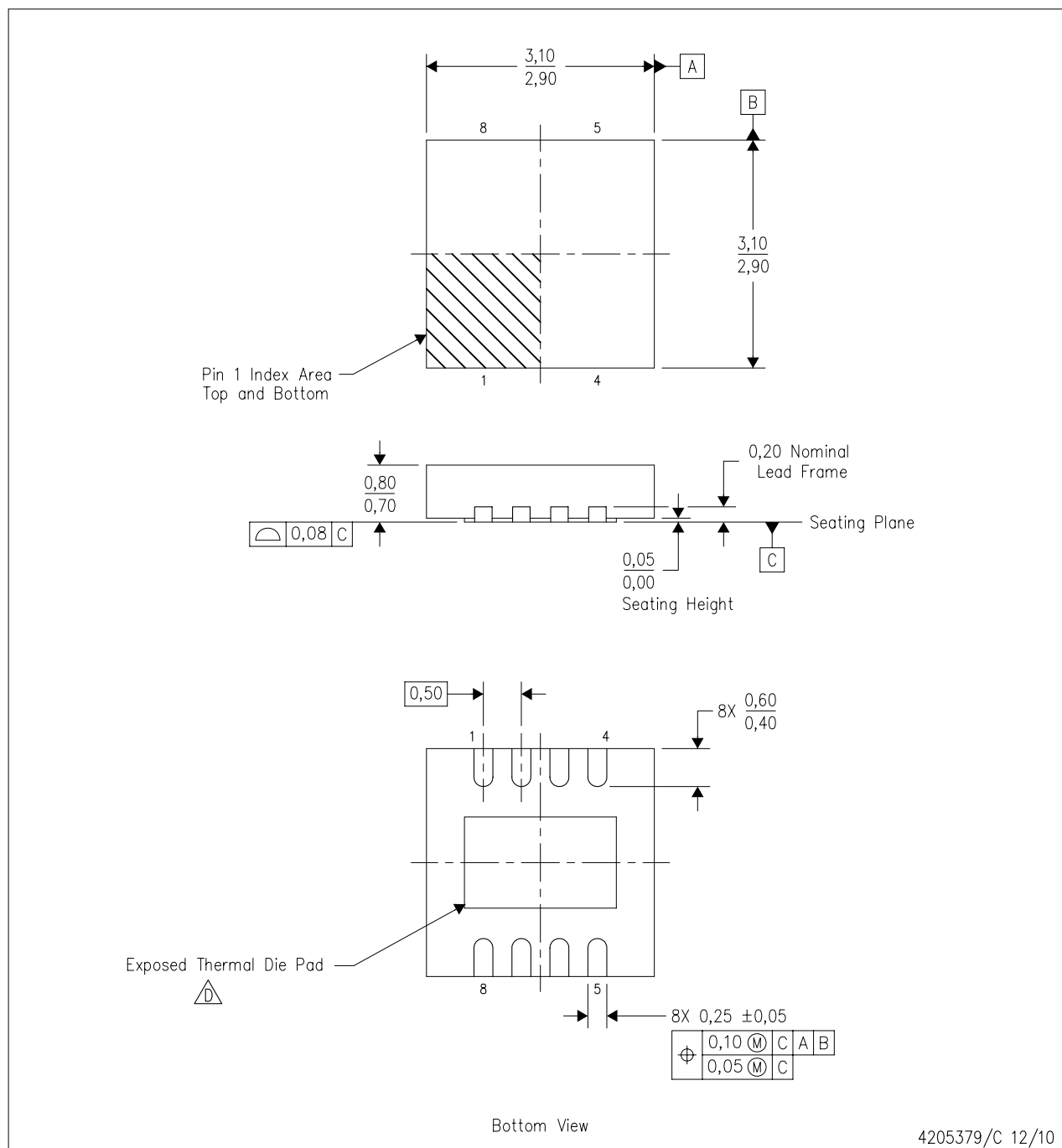
NOTES: A.   All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M−1994.
         B.   This drawing is subject to change without notice.
         C.   SON (Small Outline No−Lead) package configuration.
         D.   The package thermal pad must be soldered to the board for thermal and mechanical performance.
              See the Product Data Sheet for details regarding the exposed thermal pad dimensions.
         E.   JEDEC MO−229 package registration pending.

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INSTRUMENTS
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THERMAL PAD MECHANICAL DATA

DRG (S−PWSON−N8)   PLASTIC SMALL OUTLINE NO−LEAD

THERMAL INFORMATION

This package incorporates an exposed thermal pad that is designed to be attached directly to an external heatsink. The thermal pad must be soldered directly to the printed circuit board (PCB). After soldering, the PCB can be used as a heatsink. In addition, through the use of thermal vias, the thermal pad can be attached directly to the appropriate copper plane shown in the electrical schematic for the device, or alternatively, can be attached to a special heatsink structure designed into the PCB. This design optimizes the heat transfer from the integrated circuit (IC).

For information on the Quad Flatpack No−Lead (QFN) package and its advantages, refer to Application Report, QFN/SON PCB Attachment, Texas Instruments Literature No. SLUA271. This document is available at www.ti.com.

The exposed thermal pad dimensions for this package are shown in the following illustration.

PIN 1 INDICATOR
1,20±0,10
Exposed Thermal Pad
1   4
8   5
2,00±0,10
Bottom View
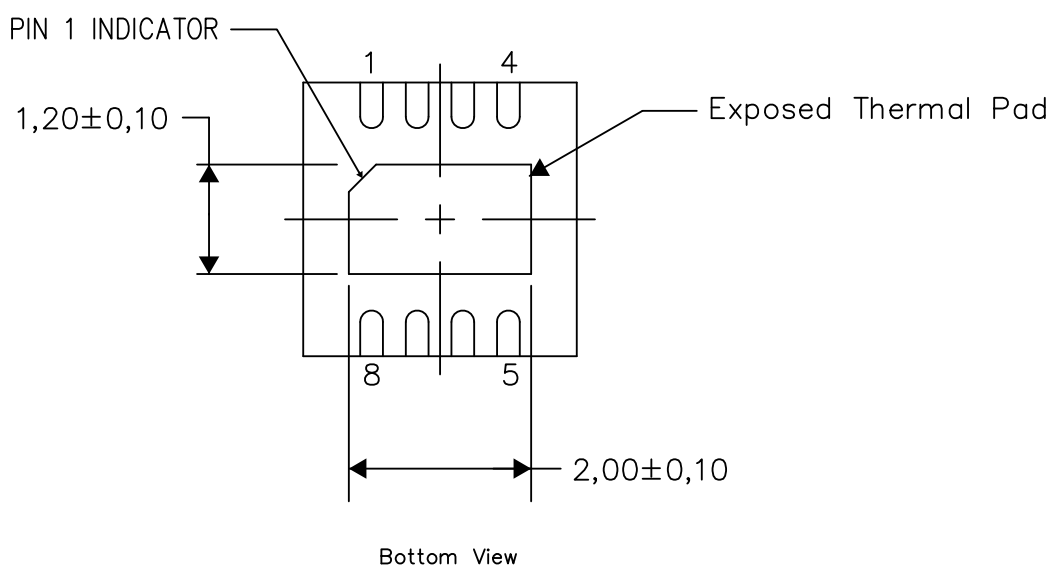
Exposed Thermal Pad Dimensions

4206881−2/H 12/13

NOTE: All linear dimensions are in millimeters

LAND PATTERN DATA

DRG (S−PWSON−N8)　　　　PLASTIC SMALL OUTLINE NO−LEAD

Example Board Layout

Note D

6x0,5

2x0,30

3,8　1,9　1,2

2x1,2

2,0

2x Via
Keep Out Area

Non Solder Mask
Defined Pad

R0,14　0,08

Solder Mask Opening
(Note F)

0,95
0,07
All around

0,28

Pad Geometry
(Note C)

Example Stencil Design
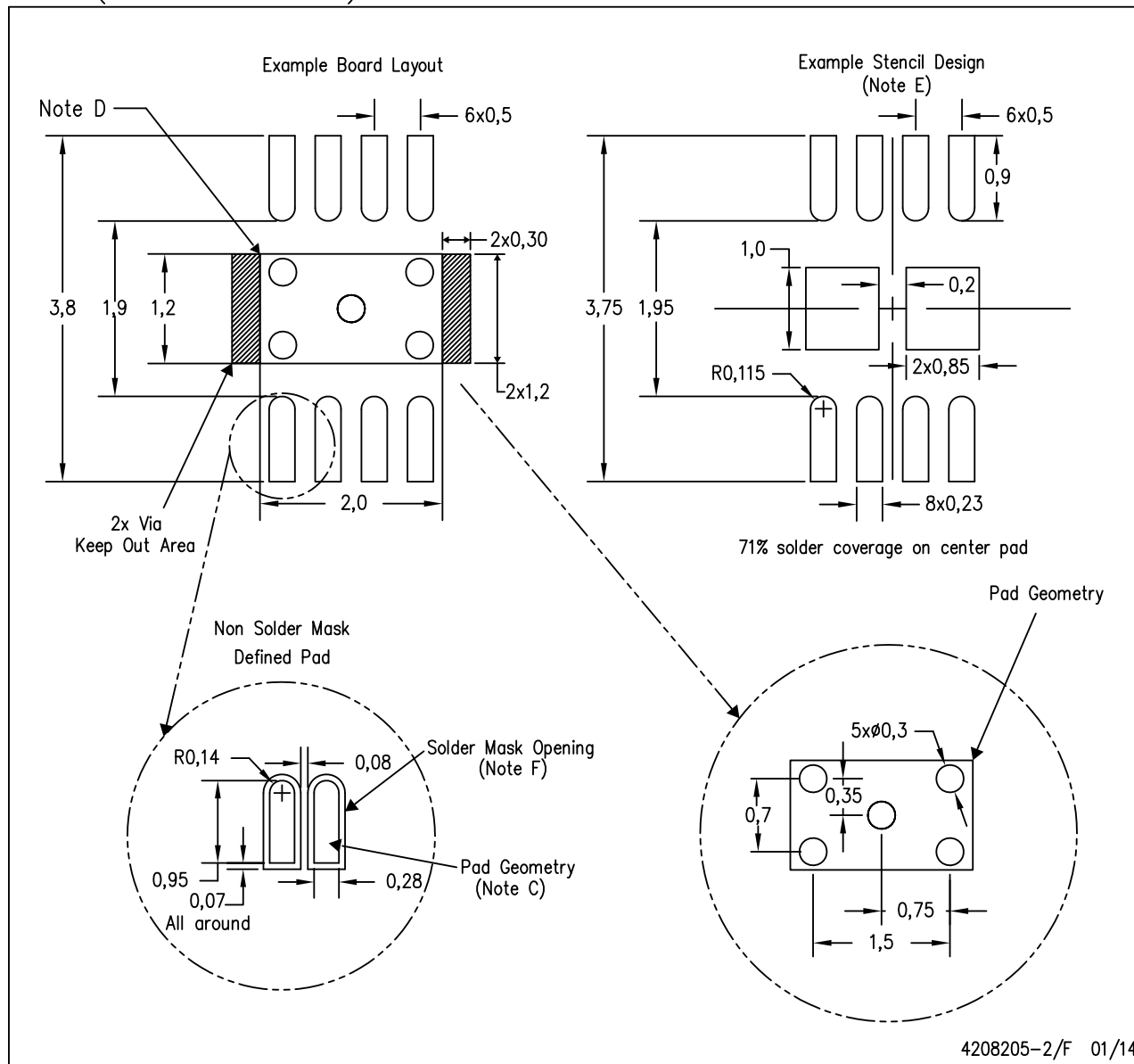(Note E)

6x0,5

0,9

1,0

0,2

3,75　1,95

R0,115

2x0,85

8x0,23

71% solder coverage on center pad

Pad Geometry

5xØ0,3

0,7

0,35

0,75

1,5

4208205−2/F　01/14

NOTES:　A.　All linear dimensions are in millimeters.
　　　　B.　This drawing is subject to change without notice.
　　　　C.　Publication IPC−SM−782 is recommended for alternate designs.
　　　　D.　This package is designed to be soldered to a thermal pad on the board.　Refer to Application Note, Quad Flat−Pack
　　　　　　Packages, Texas Instruments Literature No. SLUA271, and also the Product Data Sheets
　　　　　　for specific thermal information, via requirements, and recommended board layout.　These documents are available at
　　　　　　www.ti.com <http://www.ti.com>.
　　　　E.　Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release.　Customers should
　　　　　　contact their board assembly site for stencil design recommendations.　Refer to IPC 7525 for stencil design considerations.
　　　　F.　Customers should contact their board fabrication site for minimum solder mask web tolerances between signal pads.

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INSTRUMENTS
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MECHANICAL DATA

D (R−PDSO−G8)   PLASTIC SMALL OUTLINE

4040047−3/M   06/11
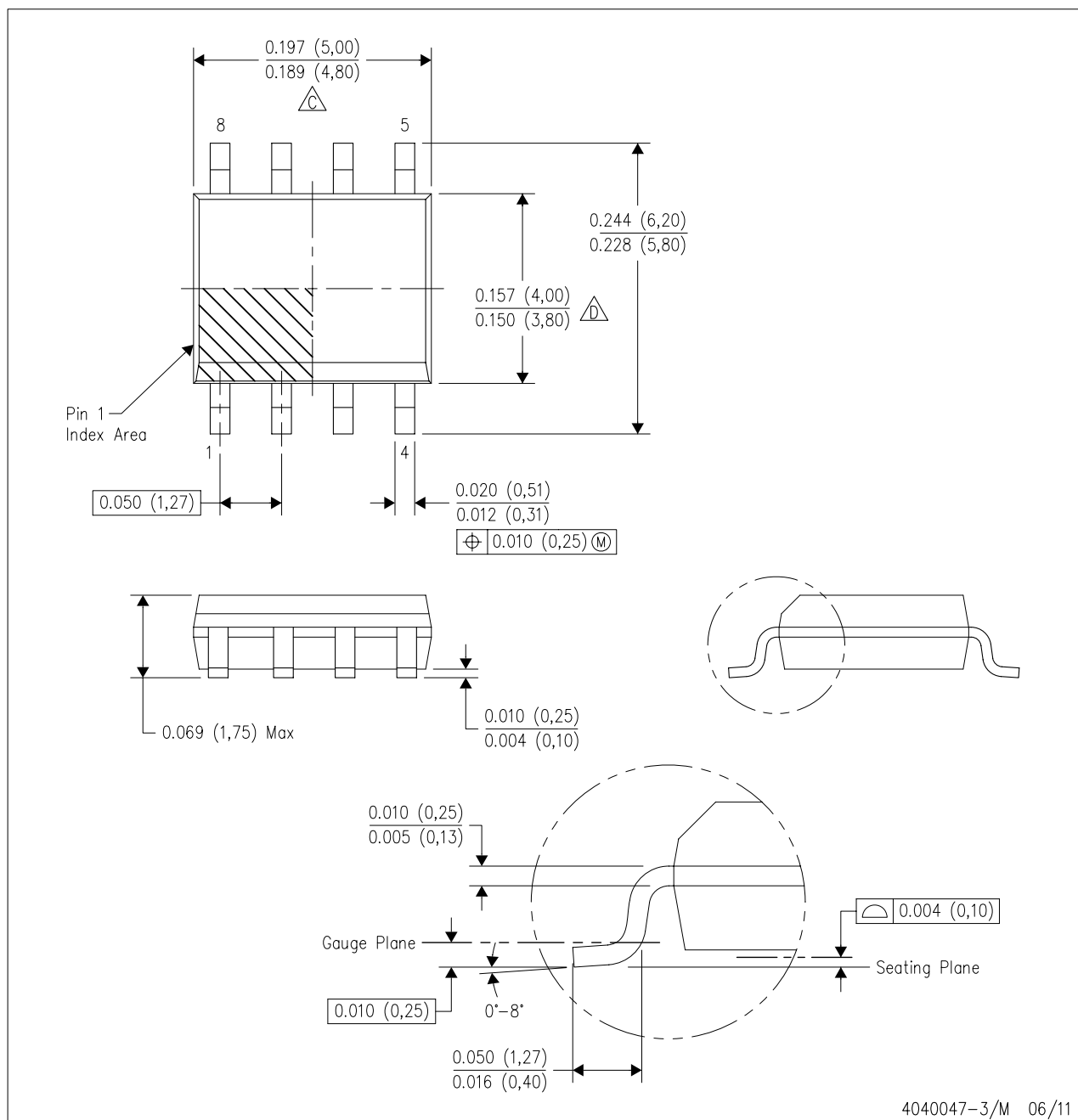
NOTES: A.   All linear dimensions are in inches (millimeters).
         B.   This drawing is subject to change without notice.
         C.   Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall
              not exceed 0.006 (0,15) each side.
         D.   Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
         E.   Reference JEDEC MS−012 variation AA.

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LAND PATTERN DATA

D (R−PDSO−G8)   PLASTIC SMALL OUTLINE

Example Board Layout
(Note C)

Stencil Openings
(Note D)

6x1,27

5,40

8x0,55

6x1,27

8x1,50

5,40

Example
Non Soldermask Defined Pad

Example
Pad Geometry
(See Note C)

Example
Solder Mask Opening
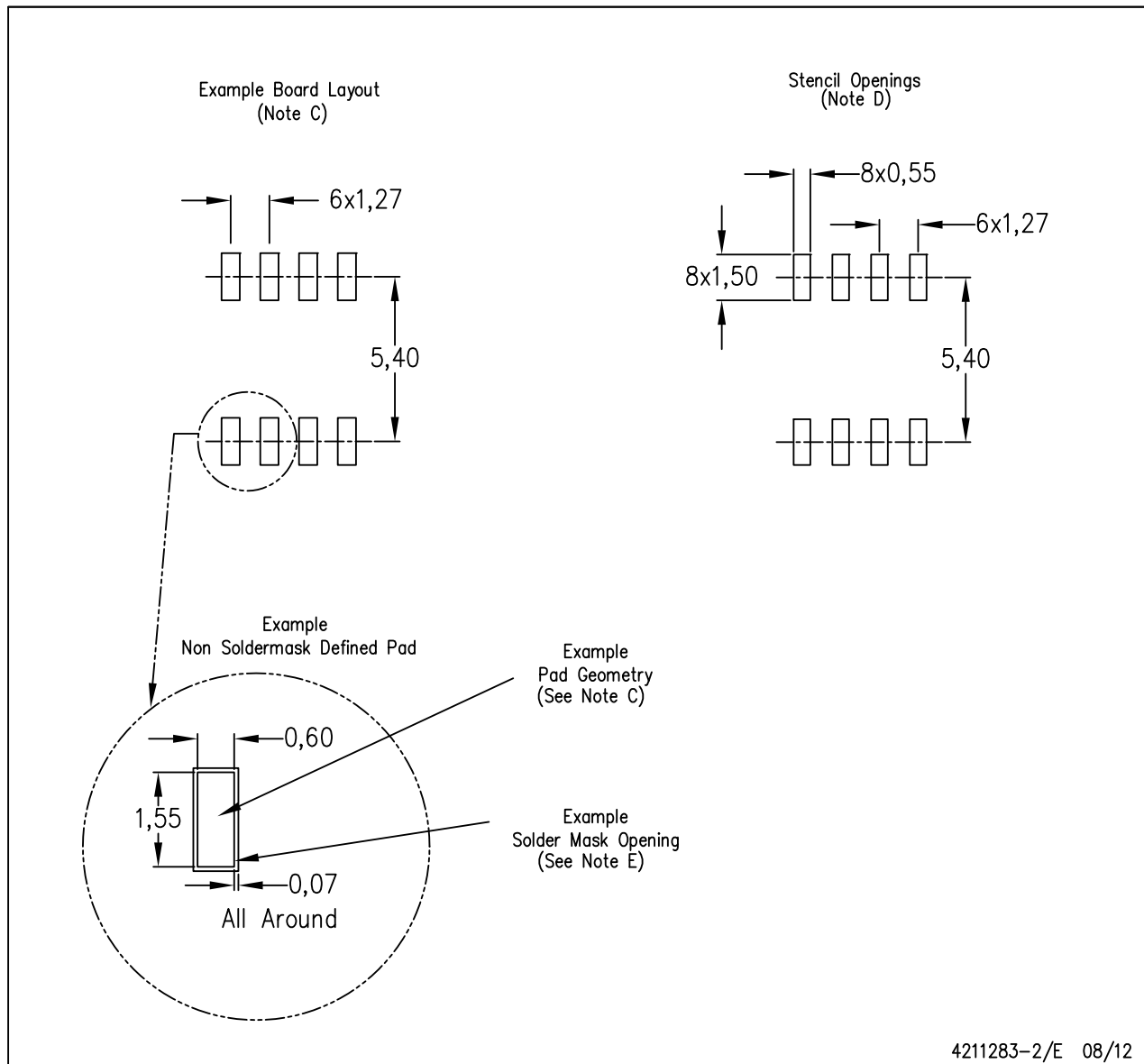(See Note E)

0,60

1,55

0,07

All Around

4211283−2/E 08/12

NOTES: A. All linear dimensions are in millimeters.
         B. This drawing is subject to change without notice.
         C. Publication IPC−7351 is recommended for alternate designs.
         D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should
             contact their board assembly site for stencil design recommendations. Refer to IPC−7525 for other stencil recommendations.
         E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.

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